Table 1 Comparison of data storage technologies. (Data drawn from public sources and HP internal research)

	Memristor	PCIM	STT- RAM	DRAM	Flash	HD
Chip area per bit (F²)	4	8–16	14-64	6–8	4-8	n/a
Energy per bit (pJ) <sup>2</sup>	0.1-3	2-100	0.1-1	2-4	101-10-	10 <sup>€</sup> −10 <sup>7</sup>
Read time (ns)	<10	20–70	10–30	10–50	25,000	5-8×10°
Write time (ns)	20–30	50–500	13 <b>~9</b> 5	10-50	200,000	5-8×10 <sup>6</sup>
Retention	>10 years	<10 <del>ye</del> ars	Weeks	<second< td=""><td>~10 years</td><td>~10 <del>ye</del>ars</td></second<>	~10 years	~10 <del>ye</del> ars
Endurance (cycles)	~10 <sup>12</sup>	10 <sup>7</sup> -10 <sup>\$</sup>	10 <sup>15</sup>	>1017	10³−10€	10 <sup>15</sup> ?
3D capability	Yes	No	No	No	Yes	n/a